

Axial Ratio Bandwidth Enhancement of 60-GHz Substrate Integrated Waveguide-Fed Circularly Polarized LTCC Antenna Array

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Abstract—A substrate integrated waveguide (SIW)-fed circularly polarized (CP) antenna array with a broad bandwidth of axial ratio (AR) is presented for 60-GHz wireless personal area networks (WPAN) applications. The widened AR bandwidth of an antenna element is achieved by positioning a slot-coupled rotated strip above a slot cut onto the broadwall of an SIW. A 4×4 antenna array is designed and fabricated using low temperature cofired ceramic (LTCC) technology. A metal-topped via fence is introduced around the strip to reduce the mutual coupling between the elements of the array. The measured results show that the AR bandwidth is more than 7 GHz. A stable boresight gain is greater than 12.5 dBic across the desired bandwidth of 57–64 GHz.

Index Terms—Antenna array, axial ratio, circular polarization, low temperature cofired ceramic, substrate integrated waveguide.

I. INTRODUCTION

WITH THE progress in high data rate wireless technologies, wireless personal area networks (WPAN) with an available spectrum of 57–64 GHz have been proposed for short-range communication applications [1]. Due to high operating frequencies and wide operating bandwidth, the design of antennas at 60-GHz bands becomes challenging [2], [3]. Low temperature cofired ceramic (LTCC) technology is an excellent candidate for the millimeter wave (mmW) antenna design because of its merits of multilayer configuration, flexible metalization, and low fabrication tolerance [3]–[6]. Compared with conventional multilayer print circuit board (PCB) technology, the LTCC technology is easier in the realization of blind vias and across-layer connection by vias.

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To compensate for the high path loss at mmW bands, an antenna array with high gain is more preferable for mmW systems. However, the gain enhancement of the antenna array is limited by the loss caused by its feeding network, such as a microstrip-line feeding network. Therefore, substrate integrated waveguide feeding network is widely used at the mmW bands because of its low transmission loss [7].

Furthermore, the circularly polarized (CP) antenna arrays have been used to improve the quality of the high-speed wireless links at the 60-GHz bands [8], [9]. However, the operating bandwidth of 7 GHz for both impedance matching and axial ratio (AR) is really a challenge for antenna design. Several methods were proposed to improve the AR bandwidth of an antenna array [10]–[13]. For example, a 4×2 circularly polarized slot array loaded by ellipse strip was proposed [10], achieving a bandwidth of 34.6% for the AR lower than 3.3 dB at 60 GHz with the gain greater than 8 dBi. A 2×2 circularly polarized cavity-backed aperture antenna array was reported with the AR bandwidth of 50% at 10 GHz with the gain greater than 6 dBic [11]. It should be noted that the designs presented in [10]–[13], the sequentially rotated feed technique was used to achieve the AR bandwidth. Such feeding structures are easily configured by a microstrip-line structure which may cause high loss at mmW bands. The CP array designs achieved the 3-dB AR bandwidth of 4% at the 60-GHz bands [8], [9]. Therefore, the combined design considerations of the AR bandwidth, gain, and feeding structure complexity become the unique design challenge at the mmW bands.

In [14]–[17], a CP antenna was designed using a waveguide-fed structure, and also for the array applications at 12 GHz. The CP antenna consists of a slot-coupled rotated dipole above the feeding slot cut onto the broadwall of a waveguide. Such a dipole-slot antenna has the merits of simple feeding structure and geometry, suitable for SIW-fed antenna array design on LTCC. However, such an antenna element and array suffer narrow AR bandwidth, typically of 4%.

In this paper, a slot-coupled rotated strip with a metal-topped via fence is proposed as an element to widen the AR bandwidth of an antenna array operating at the 60-GHz bands. A 4×4 SIW-fed CP antenna array is fabricated using LTCC technology and tested.

II. ANTENNA ELEMENT DESIGN

Fig. 1 shows the proposed antenna element. It is composed of a 10-layer LTCC substrate of Ferro A6-M with $\epsilon_r = 5.9 \pm 0.2$,

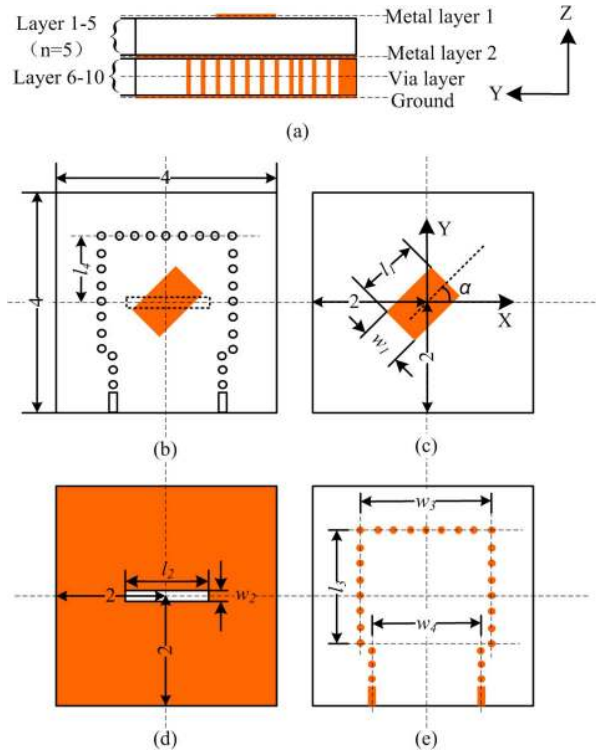


Fig. 1. Geometry and dimensions of the proposed antenna element on LTCC (unit: mm): (a) side view; (b) top view; (c) metal layer 1; (d) metal layer 2; (e) middle layer.

TABLE I
DETAILED DIMENSIONS OF THE ELEMENT (UNIT: MM)

l_1	w_1	α	l_2	w_2	l_3	w_3	l_4	w_4
0.92	0.44	45°	1.1	0.2	1.75	2	1.25	1.8

$\tan \delta = 0.002$ at 60 GHz. The thickness of the substrate layer is $b = 0.095$ mm and the metal layer $t = 0.015$ mm. The conductor used (in dark color) for the metallization and vias is Au with the conductivity of 4.56×10^7 S/m. The antenna element comprises three parts: a rectangular strip rotated by an angle of α from x -axis, a feeding slot cut onto the broadwall of the SIW, and a cavity at the end of the SIW for impedance matching. The SIW feeding structure is formed in Layers 6–10 and the strip is positioned five layers above the feeding slot. The diameter and the pitch of the vias in the SIW are 0.1 and 0.25 mm, respectively.

The detailed optimized parameters are tabulated in Table I. The optimization is conducted using the software package of CST Microwave Studio that is based on a finite integration method. Figs. 2 and 3 show the simulated reflection coefficient, AR bandwidth, and gain of the antenna element. The bandwidths of the -10 dB reflection coefficient and the 3 dB AR cover the 60-GHz WPAN band of 57–64 GHz. Within the operating bandwidth, the gain is greater than 4.59 dBi.

The dipole-slot antenna can be used to generate CP radiation as shown in [14]–[17]. In order to widen the AR bandwidth of dipole-slot structure, a rectangular patch is used to replace the thin dipole as shown in Fig. 1. The patch element introduces additional CP radiation because the additional one-wavelength mode appears along the edge of the patch element where the current is excited.

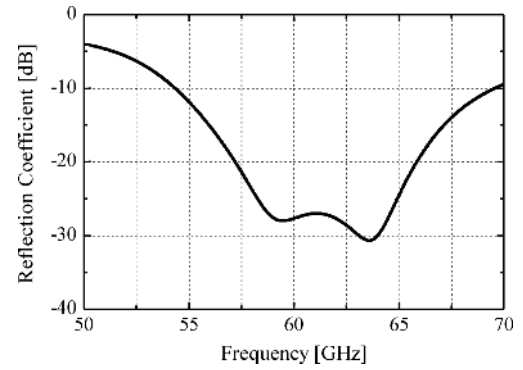


Fig. 2. Simulated reflection coefficient of the antenna element.

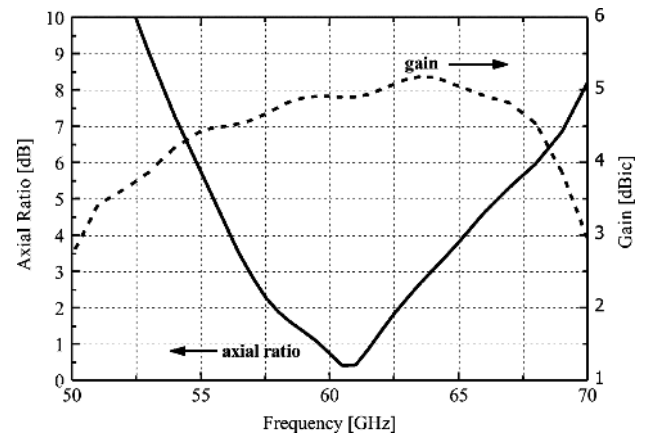


Fig. 3. Simulated AR and gain of the antenna element.

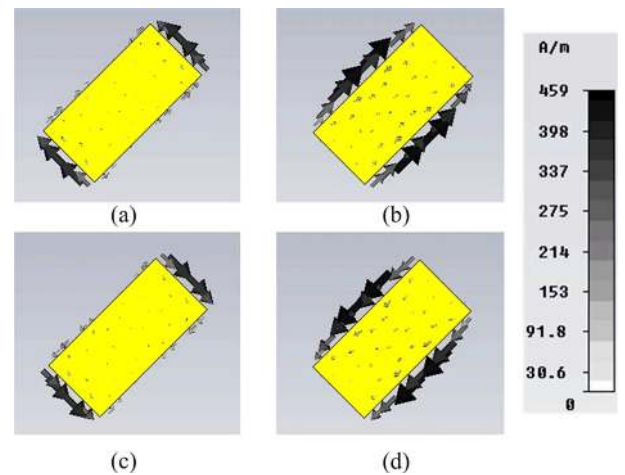


Fig. 4. Current distribution on a rotated patch at 60 GHz with different phase: (a) 0°; (b) 90°; (c) 180°; (d) 270°.

As shown in Fig. 4, two one-wavelength modes are at the edges of patch. At the phase of 0°, 90°, 180°, and 270°, the current appearing periodically along the broad or narrow edges of the patch flows in a rotated direction, which generates a left-hand CP radiation. Such additional CP radiation broadens the overall AR bandwidth up to 7.16 GHz (56.91–64.07 GHz) as shown in Fig. 3.

The AR bandwidth is sensitive to slot and patch-related parameters, namely the thickness of the substrate layer (b), the rotated angle of the strip (α), as well as the dimensions of the

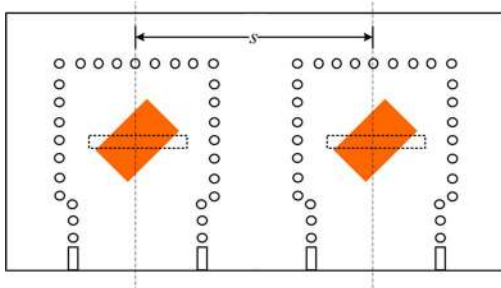
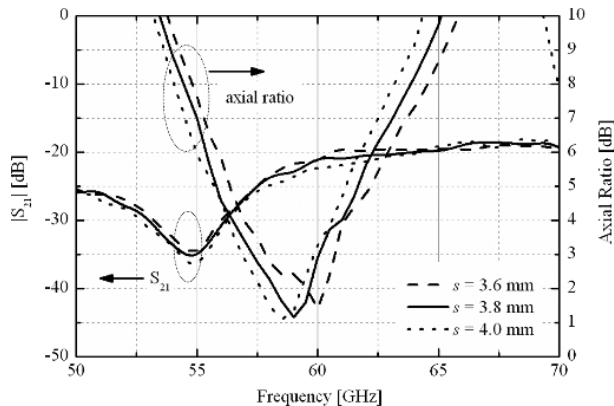


Fig. 5. Two-element array.

Fig. 6. Simulated $|S_{21}|$ and AR with different s .

strip (l_1 and w_1). The spacing between the strip and slot determines the phase difference of orthogonal modes. The rotated angle (α) of the strip is tuned to achieve the equal amplitudes for the orthogonal modes. The center frequency of AR bandwidth shifts down as increasing α . The dimensions of the strip (l_1 and w_1) affect the center frequency of the AR bandwidth. The dimensions of the feeding slot (l_2 and w_2) have less effect to AR bandwidth. However, the feeding slot is important for energy coupling to the rotated strip. It is also found that the parameters l_4 , l_3 , and w_3 hardly affect the CP performance but impedance matching. The cavity at the end of the SIW acts as an impedance transformer between the feeding slot and the SIW.

III. ANTENNA ARRAY DESIGN

The mutual coupling between the two adjacent elements of the array is examined. Fig. 5 shows the array configuration with two proposed elements separated at a center distance s . The $|S_{21}|$ and AR response with different s are simulated as shown in Fig. 6. Clearly, the AR bandwidth reduces dramatically from 11.7% in Fig. 3 to 4.2% in Fig. 6 because of the interelement mutual coupling.

A. Mutual Coupling Reduction

The mutual coupling is mainly caused by the surface wave between the elements. The surface wave propagates along the metal Layer 2, where the feeding slot is positioned. Due to the surface wave, the phase difference between two orthogonal modes in single element has been changed. To maintain the AR bandwidth in the array environment, the mutual coupling must be reduced. In [18], a metal-topped quarter-wavelength type choke structure is designed to suppress the surface waves.

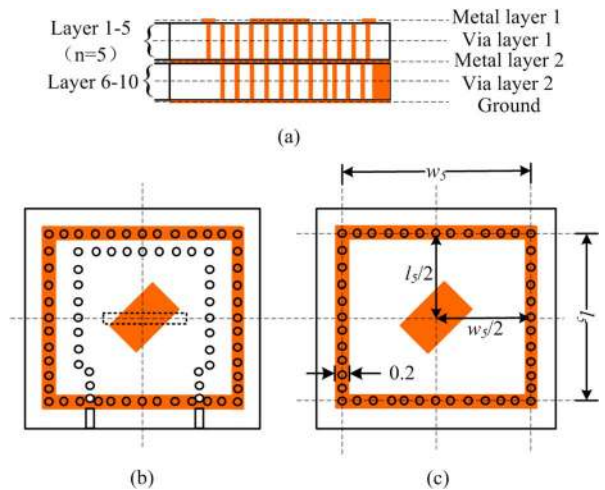
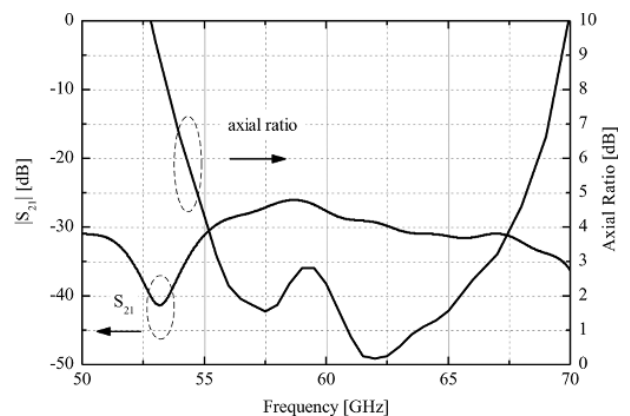


Fig. 7. Geometry of the proposed element with metal-topped via fence (Unit: mm). (a) side view; (b) top view; (c) metal layer 1.

Fig. 8. Simulated $|S_{21}|$ and AR with $s = 3.8$ mm.

To maintain the magnetic boundary condition to the radiating aperture, the choke is positioned at a distance of approximately a half wavelength from the radiating element. However, in the array design, the distance between two adjacent elements is restricted by other radiation performance, such as sidelobe level and so on. Therefore, we propose a metal-topped via fence around the element with a small distance to block the surface waves as shown in Fig. 7. The uniform width of the metal top is 0.2 mm. The distance l_5 and w_5 are optimized for both the AR bandwidth and impedance matching with $l_5 = w_5 = 3$ mm ($0.6\lambda_0$ at 60 GHz). Between two elements, two rows of via-fence are positioned to block the surface waves.

The effect of the via-fence on the AR of the two-element array and the interelement mutual coupling is shown in Fig. 8. The AR bandwidth is much wider than that without the via-fence as shown in Fig. 6, and is even wider than the single element. The isolation between the two adjacent elements is also improved more than 25 dB using the metal-topped via-fence.

The single element with a metal-topped via-fence has also been simulated. Figs. 9 and 10 show the simulated reflection coefficient, AR bandwidth, and gain. The via-fence operates as a cavity load, which is helpful for impedance bandwidth improvement [3]. The cavity loading also provides additional freedom

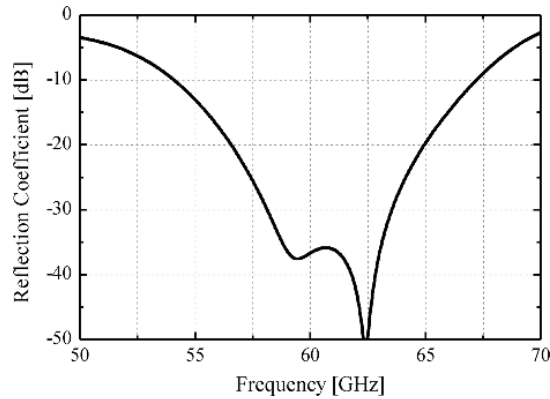


Fig. 9. Simulated reflection coefficient of the single antenna element with metal-topped via-fence.

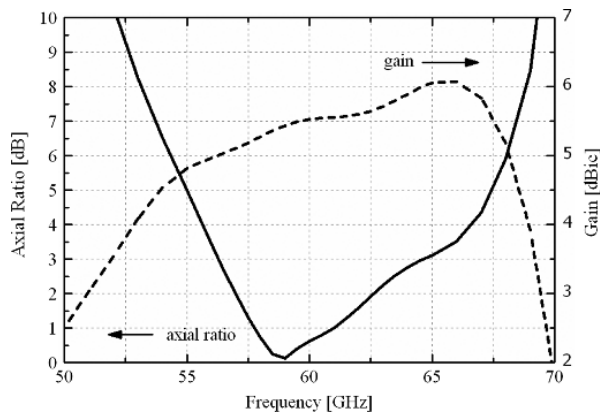


Fig. 10. Simulated AR and gain of the single antenna element with metal-topped via-fence.

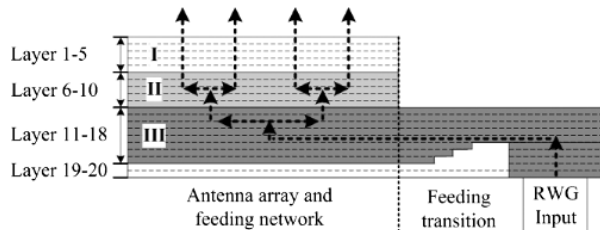


Fig. 11. Side view of the 4×4 -element array with feed transition.

in AR optimization by tuning l_5 and w_5 . The reflection of surface wave can be utilized to tune the amplitudes in orthogonal directions. Due to cavity effect, the gain of single element is also increased as shown in Fig. 10.

B. Antenna Array With Feeding Structure

Fig. 11 shows the 4×4 -element antenna array with the feeding network on the left hand side and the stepped feeding transition for measurement on the right hand side. The feeding network and transition are modified from the feeding structure of [3]. A 20-layered LTCC substrate is used with the total thickness of 2.02 mm (20 substrate layers and 8 metal layers). The arrow with a dashed line indicates the RF signal trace. The antenna array has three regions, which are shown in Figs. 12–14.

Region I includes five layers (Layers 1–5). The 16 elements are positioned with a distance of 3.8 mm ($0.76\lambda_0$ at 60 GHz)

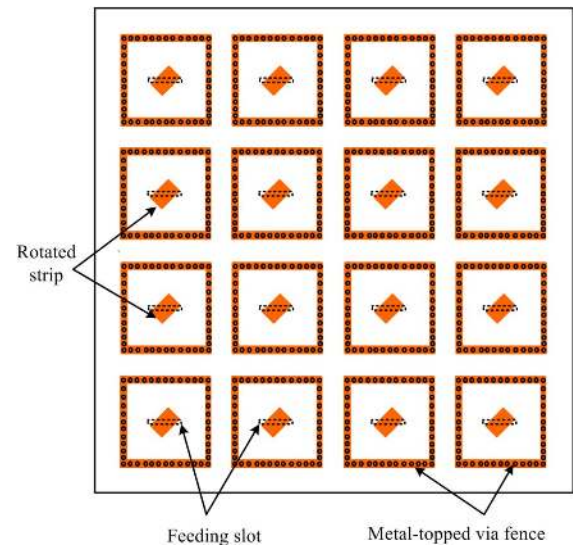


Fig. 12. Top view of Region I.

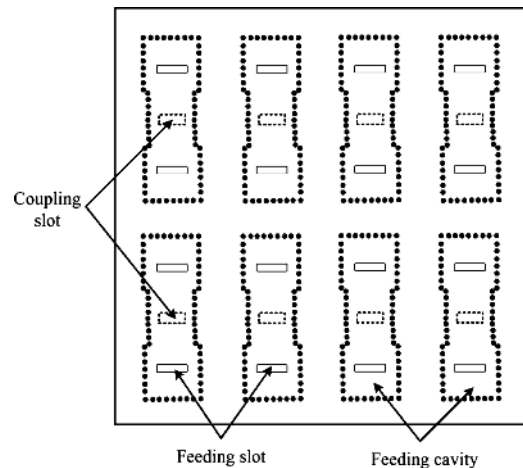


Fig. 13. Top view of region II.

between two adjacent elements in both horizontal and vertical directions. The rotated strip and metal top of the via-fence are printed on the top layer (Layer 1), and the via-fence is formed from Layer 1 to 5. As shown in Fig. 13, Region II also includes five layers (Layers 6–10). The 4×2 -element subarrays with feeding cavities and feeding slots (solid line) are arranged to feed the element. The feeding slots are etched onto the top of Layer 6, and the cavity is formed from Layer 6 to 10. Each subarray couples from Region III by a coupling slot (dashed line). The coupling slot is etched onto the top of Layer 11. The Region III includes 10 layers (Layers 11–20). As shown in Fig. 14, a 1-to-8 power divider is arranged from Layer 11 to 18 to couple the energy to the subarrays through the slots. The detailed dimensions of the power divider are illustrated in Fig. 15. Another part of Region III is the SIW-RWG transition with 10 layers (layer 11–20). The antenna array is fed through a WR-15 RWG. The stepped transition serves as an impedance transformer between the RWG and SIW in Layers 11–18 [3]. Fig. 16 shows the detailed dimensions of the transition. The optimized dimensions of the elements in the array are: $\alpha = 39^\circ$, $l_5 = w_5 = 2.8$ mm, and the other parameters are kept the same as the element design.

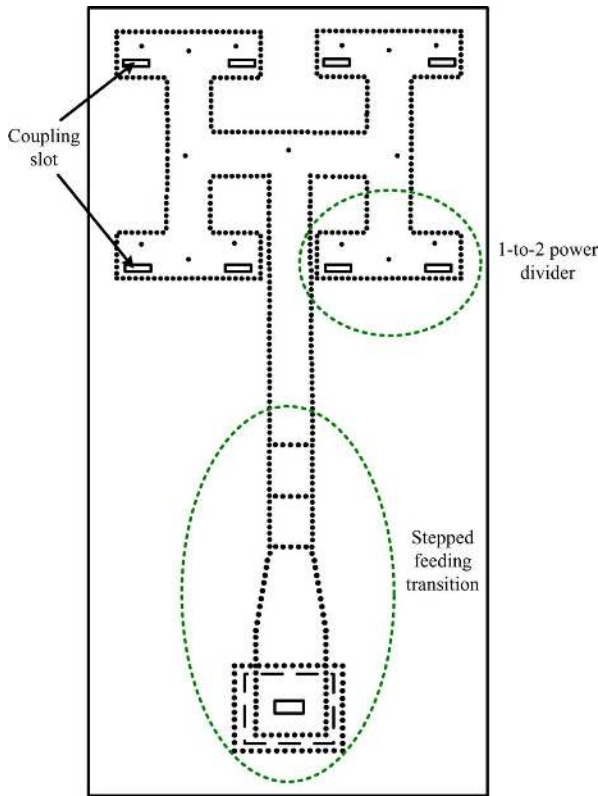


Fig. 14. Top view of Region III.

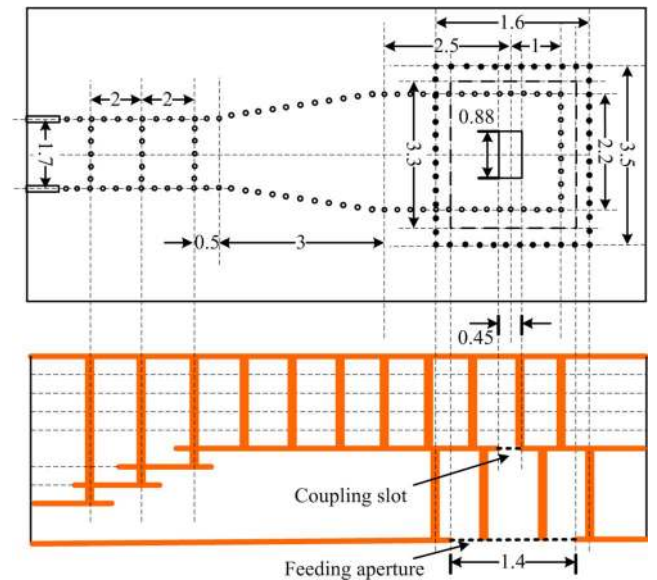


Fig. 16. Geometry and dimensions of the stepped feeding transition in Region III.

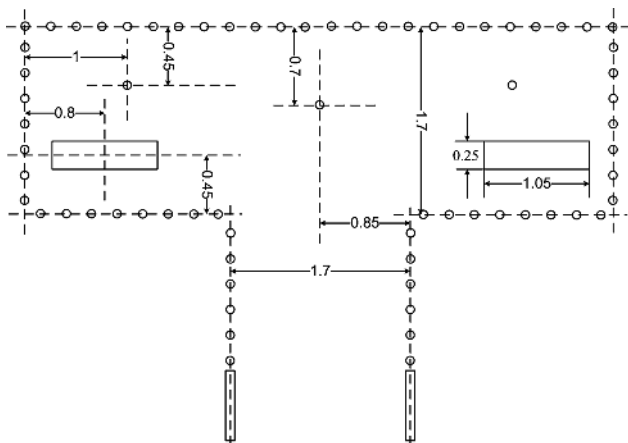


Fig. 15. Geometry and dimensions of the 1-to-2 power divider.

IV. EXPERIMENTAL RESULTS

The proposed 4×4 -element array with feeding transition was fabricated using LTCC as shown in Fig. 17(a). The overall size of the antenna area (white color) is $15.4 \times 15.4 \text{ mm}^2$. The holes in the feeding area are used for connecting and accurately positioning with the RWG flange. The antenna was measured using a self-built mmW antenna measurement system at Institute for Infocomm Research, Singapore, as shown in Fig. 17(b).

The measured results of the proposed antenna array are illustrated in Figs. 18 and 19, and compared with simulated results. The bandwidth of reflection coefficient better than -6 dB is from 56.65 GHz to 65.75 GHz . The measured 3 dB AR bandwidth ranges from 60.2 GHz , up to 67 GHz (due to the limitation of vector network analyzer). The measured AR bandwidth

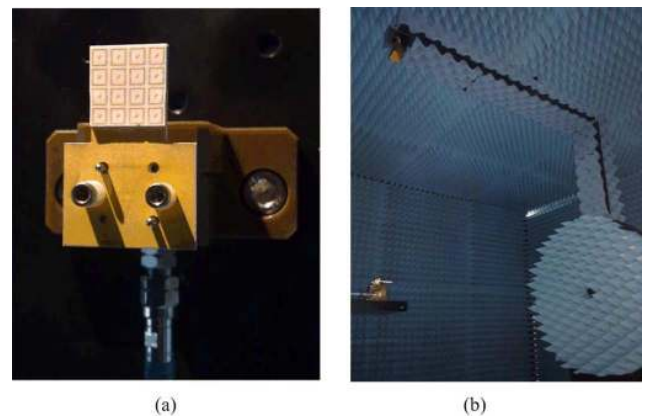


Fig. 17. Photograph of (a) array prototype and (b) measurement system.

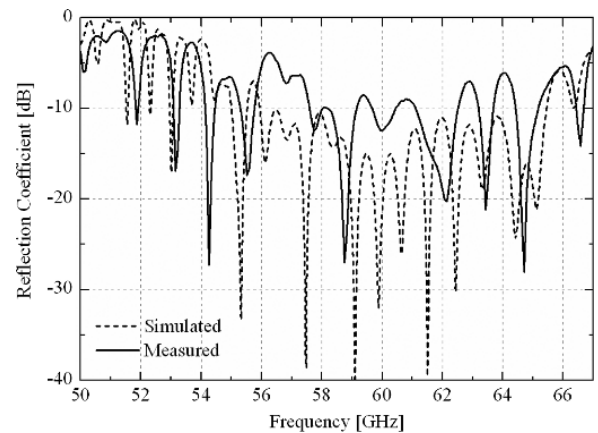


Fig. 18. Simulated and measured reflection coefficient of the antenna array.

of more than 7 GHz is as wide as the simulated while the band shifts to the higher end, which is mainly from the shrinking of LTCC fabrication.

The parametric study of the substrate layer thickness (b) is illustrated in Figs. 20 and 21. In Fig. 20, the decreasing b degrades the AR and shifts the resonant frequency upwards. And the

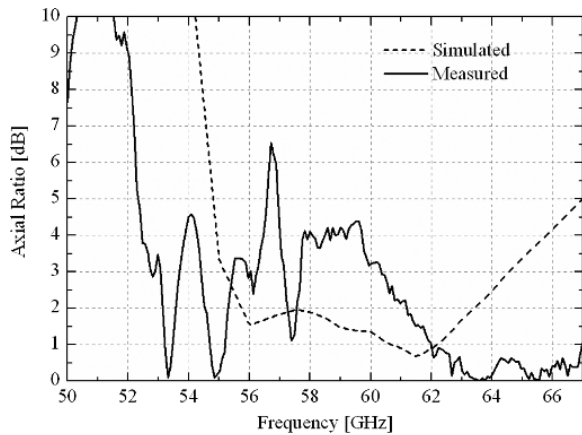


Fig. 19. Simulated and measured axial ratio of the antenna array.

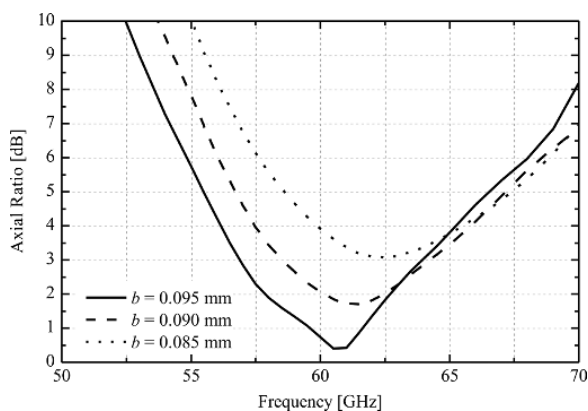


Fig. 20. Simulated AR of the antenna element with different b .

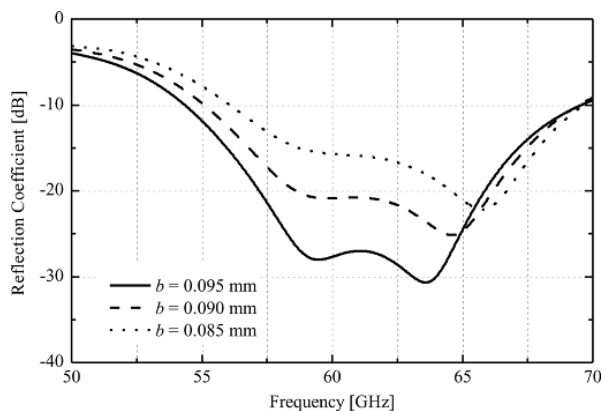


Fig. 21. Simulated reflection coefficient of the antenna element with different b .

impedance matching is also deteriorated as illustrated in Fig. 21. The thicknesses difference of the antenna prototype is observed as shown in Fig. 22. Compared with the designed thickness of 2.02 mm, the thickness of the antenna prototype is smaller and varies over the area of the antenna array. As discussed above, the reduction of the substrate thickness degrades the AR as well as the impedance matching bandwidth, and shifts the operating frequency upwards. The measurement validates the fact that the proposed method is capable of enhancing the AR bandwidth in array design with the SIW feeding structure in LTCC.

The normalized gain patterns of the proposed antenna array were measured and simulated in the xz -plane and yz -plane at

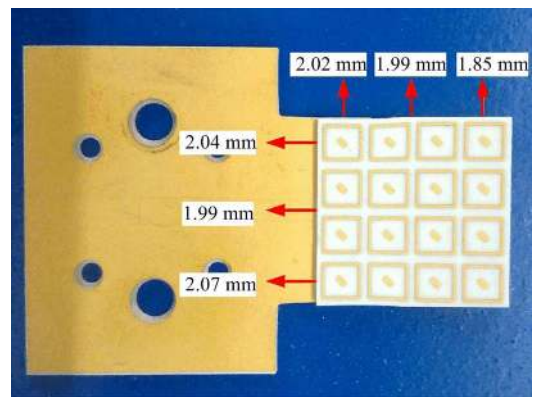
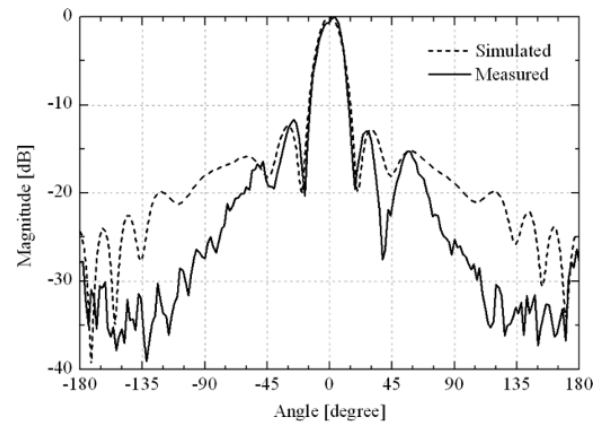
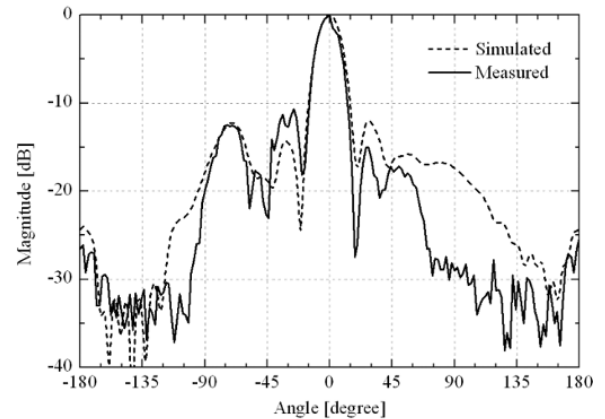


Fig. 22. The thicknesses of the antenna prototype at different positions.



(a)



(b)

Fig. 23. Simulated and measured radiation patterns of the antenna array at 60 GHz. (a) xz -plane. (b) yz -plane.

60 GHz. Usually, the gain as well as the radiation patterns of a CP antenna can be measured using the method of rotating a linear source [19]. Limited to the measurement set-up at 60 GHz bands, the gain with the horizontal and vertical polarizations instead of the gain aligned with the major and minor axes of the polarization ellipse are measured first and added together afterwards. The measurement shows good agreement with the simulation. In each plane, we measured the CP gain of the antenna at each angle and then normalized the results to the peak gain as shown in Fig. 23. The simulated and the measured sidelobe levels are lower than -10 dB.

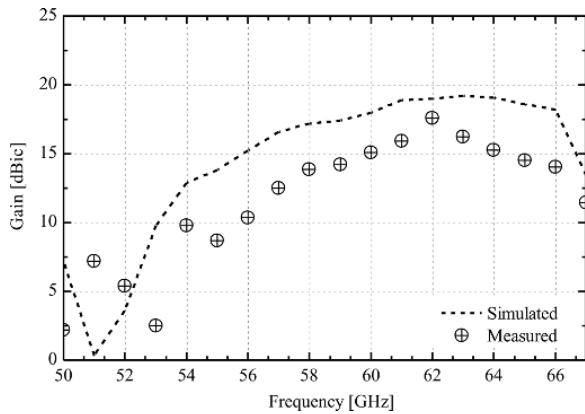


Fig. 24. Simulated and measured gains of the antenna array.

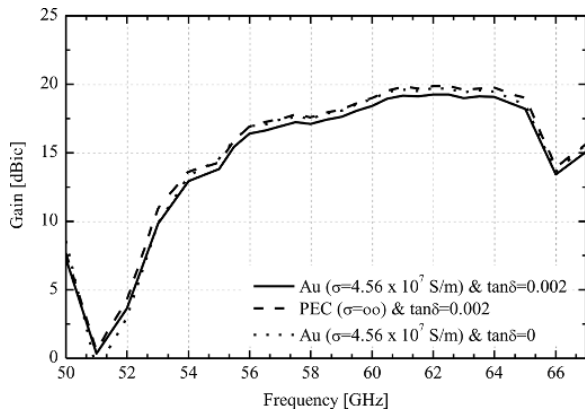


Fig. 25. Simulated gain of the antenna array with different substrates and metals.

Fig. 24 shows the measured gain of the proposed 4×4 antenna array. In the band of 57–64 GHz, the average gain is 15 dBic. Compared with the simulated results, an average gain drop of 2.5 dB comes from the deterioration of impedance matching due to the fabrication, also the deviation of the dielectric loss of the LTCC substrate and the conductivity of the metallization. Fig. 25 shows approximately 0.5 dB loss caused by the dielectric loss and metal conductivity.

V. CONCLUSION

In this paper, a 4×4 -element SIW-fed CP antenna array on LTCC has been proposed for 60-GHz applications. The AR bandwidth has been widened by adopting a rotated strip because of the additional CP radiation from the strip. In order to reduce the mutual coupling among elements in the array, a metal-topped via fence has been used to suppress the surface waves, also improve the AR bandwidth. A prototype of the proposed array has been fabricated and characterized in terms of impedance matching, AR bandwidth, radiation patterns, and gain. The measured results have shown that the 3 dB AR bandwidth covering 60.2–67 GHz has been achieved with the bore-sight gain greater than 12.5 dBic.

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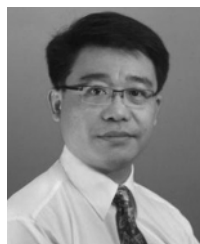
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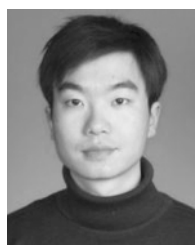
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